

## 8-Bit 40 MSPS/60 MSPS/80 MSPS A/D Converter

AD9057

#### **FEATURES**

8-Bit, Low Power ADC: 200 mW Typical
120 MHz Analog Bandwidth
On-Chip 2.5 V Reference and Track-and-Hold
1 V p-p Analog Input Range
Single 5 V Supply Operation
5 V or 3 V Logic Interface
Power-Down Mode: <10 mW
3 Performance Grades (40 MSPS, 60 MSPS, 80 MSPS)

### **APPLICATIONS**

Digital Communications (QAM Demodulators)
RGB and YC/Composite Video Processing
Digital Data Storage Read Channels
Medical Imaging
Digital Instrumentation

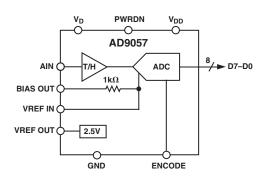
### PRODUCT DESCRIPTION

The AD9057 is an 8-bit monolithic analog-to-digital converter optimized for low cost, low power, small size, and ease of use. With 40 MSPS, 60 MSPS, or 80 MSPS encode rate capability and full-power analog bandwidth of 120 MHz, the component is ideal for applications requiring excellent dynamic performance.

To minimize system cost and power dissipation, the AD9057 includes an internal 2.5 V reference and a track-and-hold (T/H) circuit. The user must provide only a 5 V power supply and an encode clock. No external reference or driver components are required for many applications.

The AD9057's encode input is TTL/CMOS compatible, and the 8-bit digital outputs can be operated from 5 V or 3 V supplies. A

### FUNCTIONAL BLOCK DIAGRAM



power-down function may be exercised to bring total consumption to <10 mW. In power-down mode, the digital outputs are driven to a high impedance state.

Fabricated on an advanced BiCMOS process, the AD9057 is available in a space-saving 20-lead shrink small outline package (20-lead SSOP) and is specified over the industrial temperature range ( $-40^{\circ}$ C to  $+85^{\circ}$ C).

Customers desiring multichannel digitization may consider the AD9059, a dual 8-bit, 60 MSPS monolithic based on the AD9057 ADC core. The AD9059 is available in a 28-lead surface-mount plastic package (28-lead SSOP) and is specified over the industrial temperature range.

# $\begin{subarray}{c} \textbf{AD9057--SPECIFICATIONS} & (v_{\text{D}}=5 \ \text{V}, \ v_{\text{DD}}=3 \ \text{V}; \ \text{external reference}, \ \text{unless otherwise noted.}) \end{subarray}$

Parameter	Temp	Test Level	AD9 Min	0057BRS Typ	6-40 Max	AD Min	9057BR: Typ	S-60 Max	AD Min	9057BRS Typ	S-80 Max	Unit
RESOLUTION				8			8			8		Bits
DC ACCURACY												
Differential Nonlinearity  Integral Nonlinearity	25°C Full 25°C	I VI I		0.75 0.75	1.9 2.0 1.9		0.75 0.75	1.9 2.0 1.9		0.75 0.75	1.9 2.0 1.9	LSB LSB LSB
	Full	VI			2.0			2.0			2.0	LSB
No Missing Codes Gain Error <sup>1</sup>	Full 25°C Full	VI I VI	-6 -8	Guarante –2.5	+6 +8	-6 -8	Guarantee –2.5	+6 +8	-6 -8	uarantee –2.5	+6 +8	% FS % FS
Gain Tempco <sup>1</sup>	Full	V		±70			±70			±70		ppm/°C
ANALOG INPUT Input Voltage Range (Centered at 2.5 V) Input Offset Voltage	25°C 25°C Full	V I VI	-15 -25	1.0	+15 +25	-15 -25	1.0	+15 +25	-15 -25	1.0	+15 +25	V p-p mV mV
Input Resistance Input Capacitance	25°C 25°C	V V	-23	150 2		-23	150 2		-23	150 2		kΩ pF
Input Bias Current	25°C Full	I VI		6	16 25		6	16 25		6	16 25	μA μA
Analog Bandwidth BAND GAP REFERENCE	25°C	V		120			120			120		MHz
Output Voltage Temperature Coefficient	Full Full	VI V	2.4	2.5 ±10	2.6	2.4	2.5 ±10	2.6	2.4	2.5 ±10	2.6	V ppm/°C
SWITCHING PERFORMANCE Maximum Conversion Rate Minimum Conversion Rate Aperture Delay (t <sub>A</sub> )	Full Full 25°C	VI IV V	40	2.7	5	60	2.7	5	80	2.7	5	MSPS MSPS ns
Aperture Uncertainty (Jitter) Output Valid Time $(t_V)^2$ Output Propagation Delay $(t_{PD})^2$	25°C Full Full	V IV IV	4.0	5 6.6 11.5	18.0	4.0	5 6.6 9.5	14.2	4.0	5 6.6 8.0	11.3	ps rms ns ns
DYNAMIC PERFORMANCE <sup>3</sup> Transient Response Overvoltage Recovery Time Signal-to-Noise Ratio (SINAD) (With Harmonics)	25°C 25°C	V V		9 9			9 9			9 9		ns ns
$f_{IN} = 10.3 \text{ MHz}$ $f_{IN} = 76 \text{ MHz}$ Effective Number of Bits (ENOB)	25°C 25°C	I V	42	45.5 44.0		42	45 43.5		41.5	45 43.5		dB dB
$f_{IN} = 10.3 \text{ MHz}$ $f_{IN} = 76 \text{ MHz}$ Signal-to-Noise Ratio (SNR) (Without Harmonics)	25°C 25°C	I V	6.7	7.2 7.0		6.7	7.2 6.9		6.6	7.2 6.9		Bits Bits
$f_{IN} = 10.3 \text{ MHz}$ $f_{IN} = 76 \text{ MHz}$ Second Harmonic Distortion	25°C 25°C	I V	43	46.5 45.5		43	46 45		42.5	46 45		dB dB
$f_{\rm IN}$ = 10.3 MHz $f_{\rm IN}$ = 76 MHz Third Harmonic Distortion	25°C 25°C	I V	-50	-62 -54		-50	-62 -54		-50	-62 -54		dBc dBc
$f_{IN}$ = 10.3 MHz $f_{IN}$ = 76 MHz Two Tone Intermodulation	25°C 25°C	I V	-46	-60 -54		-46	-60 -54		-46	-60 -54		dBc dBc
Distortion (IMD) Differential Phase Differential Gain	25°C 25°C 25°C	V V V		-52 0.8 1.0			-52 0.8 1.0			-52 0.8 1.0		dBc Degrees %
DIGITAL INPUTS Logic 1 Voltage Logic 0 Voltage Logic 1 Current Logic 0 Current Input Capacitance Encode Pulsewidth High (t <sub>EH</sub> ) Encode Pulsewidth Low (t <sub>EL</sub> )	Full Full Full Full 25°C 25°C 25°C	VI VI VI VI IV IV	2.0 9.0 9.0	4.5	0.8 ±1 ±1 166 166	2.0 6.7 6.7	4.5	0.8 ±1 ±1 166 166	2.0 5.5 5.5	4.5	0.8 ±1 ±1 166 166	V V μA μA pF ns ns

–2– REV. D

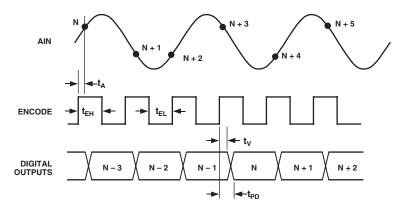
		Test	AD9	057BRS	6-40	AD	9057 <b>BR</b> 3	S-60	ADS	9057BR	S-80	
Parameter	Temp	Level	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Unit
DIGITAL OUTPUTS												
Logic 1 Voltage ( $V_{DD} = 3 \text{ V}$ )	Full	VI	2.95			2.95			2.95			V
Logic 1 Voltage ( $V_{DD} = 5 \text{ V}$ )	Full	IV	4.95			4.95			4.95			V
Logic 0 Voltage	Full	VI			0.05			0.05			0.05	V
Output Coding			Offset	Binary	Code	Offset	Binary	Code	Offset	Binary	Code	
POWER SUPPLY												
$V_D$ Supply Current ( $V_D = 5 \text{ V}$ )	Full	VI		36	48		38	48		40	51	mA
$V_{DD}$ Supply Current $(V_{DD} = 3 \text{ V})^4$	Full	VI		4.0	6.5		5.5	6.5		7.4	8.8	mA
Power Dissipation <sup>5, 6</sup>	Full	VI		192	260		205	260		220	281	mW
Power-Down Dissipation	Full	VI		6	10		6	10		6	10	mW
Power Supply Rejection Ratio												
(PSRR)	25°C	V		3			3			3		mV/V

## NOTES

Specifications subject to change without notice.

## **EXPLANATION OF TEST LEVELS**

Test Level	Description
I	100% production tested.
II	100% production tested at 25°C and sample
	tested at specified temperatures.
III	Sample tested only.
IV	Parameter is guaranteed by design and characterization testing.
V	Parameter is a typical value only.
VI	100% production tested at 25°C; guaranteed by design and characterization testing for industrial temperature range.



		MIN	TYP	MAX
t <sub>A</sub>	APERTURE DELAY		2.7 ns	
t <sub>EH</sub>	PULSEWIDTH HIGH			166 ns
t <sub>EL</sub>	PULSEWIDTH LOW			166 ns
t <sub>V</sub>	OUTPUT VALID TIME	4.0 ns	6.6 ns	
t <sub>PD</sub>	OUTPUT PROP DELAY		9.5 ns	

Figure 1. Timing Diagram

 $<sup>^{1}</sup>$ Gain error and gain temperature coefficient are based on the ADC only (with a fixed 2.5 V external reference).

<sup>2</sup>t<sub>V</sub> and t<sub>PD</sub> are measured from the 1.5 V level of the encode to the 10%/90% levels of the digital output swing. The digital output load during test is not to exceed an ac load of 10 pF or a dc current of  $\pm 40 \mu A$ .

<sup>&</sup>lt;sup>3</sup>SNR/harmonics based on an analog input voltage of -0.5 dBFS referenced to a 1.0 V full-scale input range.

<sup>&</sup>lt;sup>4</sup>Digital supply current based on  $V_{DD}$  = 3 V output drive with <10 pF loading under dynamic test conditions. <sup>5</sup>Power dissipation is based on specified encode and 10.3 MHz analog input dynamic test conditions ( $V_D$  = 5 V ± 5%,  $V_{DD}$  = 3 V ± 5%).

 $<sup>^6\</sup>mathrm{Typical}$  thermal impedance for the RS style (SSOP) 20-lead package:  $\theta_{JC}=46^{\circ}\mathrm{C/W},\,\theta_{CA}=80^{\circ}\mathrm{C/W},$  and  $\theta_{JA}=126^{\circ}\mathrm{C/W}.$ 

## **ABSOLUTE MAXIMUM RATINGS\***

$V_D, V_{DD}$
Analog Inputs $-0.5 \text{ V}$ to $V_D$ + $0.5 \text{ V}$
Digital Inputs
VREF Input $-0.5 \text{ V}$ to $V_D + 0.5 \text{ V}$
Digital Output Current 20 mA
Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Maximum Junction Temperature 150°C
Maximum Case Temperature 150°C

<sup>\*</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ORDERING GUIDE**

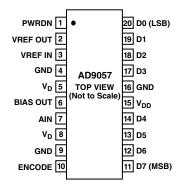
Model	Temperature Range	Package Option*
AD9057BRS-40	-40°C to +85°C -40°C to +85°C	RS-20
AD9057BRS-60	$-40^{\circ}$ C to $+85^{\circ}$ C	RS-20
AD9057BRS-80	-40°C to +85°C	RS-20
AD9057/PCB	25°C	Evaluation Board

<sup>\*</sup>RS = Shrink Small Outline Package (SSOP).

Table I. Digital Coding (VREF = 2.5 V)

<b>Analog Input</b>	Voltage Level	Digital Output
3.0 V	Positive Full Scale	1111 1111
2.502 V	Midscale +1/2 LSB	1000 0000
2.498 V	Midscale -1/2 LSB	0111 1111
2.0 V	Negative Full Scale	0000 0000

## PIN CONFIGURATION



## PIN FUNCTION DESCRIPTIONS

Pin No.	Mnemonic	Function
1	PWRDN	Power-Down Function Select; Logic High for Power-Down Mode (Digital Outputs Go to High Impedance State).
2	VREF OUT	Internal Reference Output (2.5 V typ); Bypass with 0.1 μF to Ground.
3	VREF IN	Reference Input for ADC (2.5 V typ, $\pm 10\%$ ).
4, 9, 16	GND	Ground (Analog/Digital).
5, 8	$V_{\mathrm{D}}$	Analog 5 V Power Supply.
6	BIAS OUT	Bias Pin for AC Coupling (1 k $\Omega$ to REF IN).
7	AIN	Analog Input for ADC.
10	ENCODE	Encode Clock for ADC (ADC Samples on Rising Edge of Encode).
11–14, 17–20	D7-D0	Digital Outputs of ADC.
15	$V_{DD}$	Digital Output Power Supply; Nominally 3 V to 5 V.

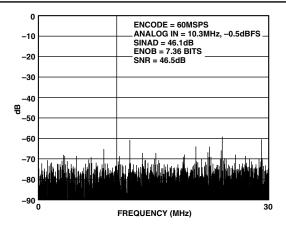
## CAUTION-

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD9057 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

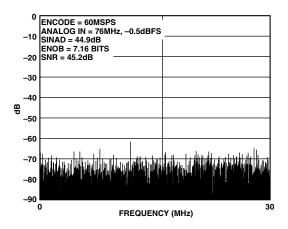


-4- REV. D

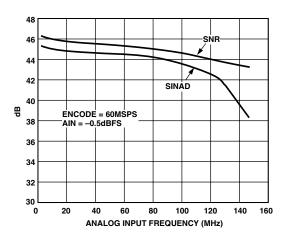
## **Typical Performance Characteristics—AD9057**



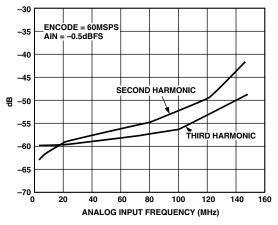
TPC 1. Spectral Plot 60 MSPS, 10.3 MHz



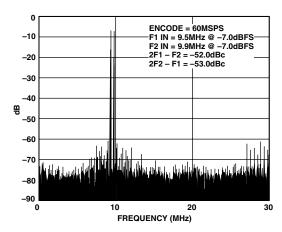
TPC 2. Spectral Plot 60 MSPS, 76 MHz



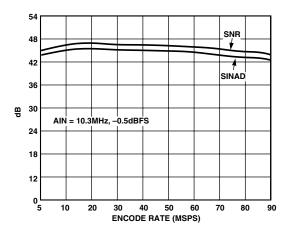
TPC 3. SINAD/SNR vs. AIN Frequency



TPC 4. Harmonic Distortion vs. AIN Frequency

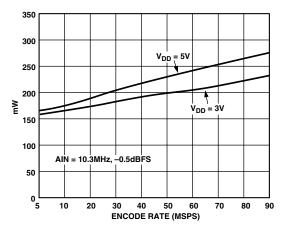


TPC 5. Two-Tone Intermodulation Distortion

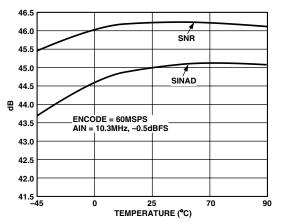


TPC 6. SINAD/SNR vs. Encode Rate

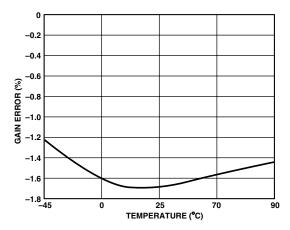
REV. D -5-



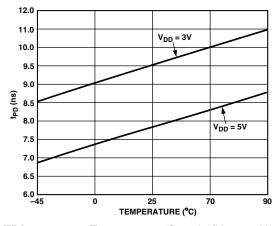
TPC 7. Power Dissipation vs. Encode Rate



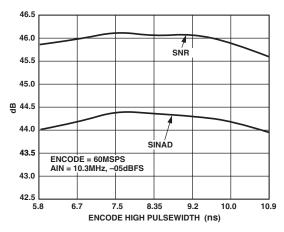
TPC 8. SINAD/SNR vs. Temperature



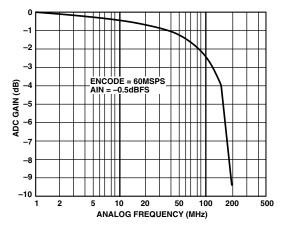
TPC 9. ADC Gain vs. Temperature (with External 2.5 V Reference)



TPC 10.  $t_{PD}$  vs. Temperature/Supply ( $V_{DD} = 3 \text{ V/5 V}$ )



TPC 11. SINAD/SNR vs. Encode Pulsewidth



TPC 12. ADC Frequency Response

-6- REV. D

### THEORY OF OPERATION

The AD9057 combines Analog Devices' proprietary MagAmp gray code conversion circuitry with flash converter technology to provide a high performance, low cost ADC. The design architecture ensures low power, high speed, and 8-bit accuracy. A single-ended TTL/CMOS compatible ENCODE input controls ADC timing for sampling the analog input pin and strobing the digital outputs (D7–D0). An internal voltage reference (VREF OUT) may be used to control ADC gain and offset or an external reference may be applied.

The analog input signal is buffered at the input of the ADC and applied to a high speed track-and-hold. The track-and-hold circuit holds the analog input value during the conversion process (beginning with the rising edge of the encode command). The track-and-hold's output signal passes through the gray code and flash conversion stages to generate coarse and fine digital representations of the held analog input level. Decode logic combines the multistage data and aligns the 8-bit word for strobed outputs on the rising edge of the encode command. The MagAmp/Flash architecture of the AD9057 results in three pipeline delays for the output data.

## **USING THE AD9057**

## **Analog Inputs**

The AD9057 provides a single-ended analog input impedance of 150 k $\Omega$ . The input requires a dc bias current of 6  $\mu$ A (typical) centered near 2.5 V (±10%). The dc bias may be provided by the user or may be derived from the ADC's internal voltage reference. Figure 2 shows a low cost dc bias implementation allowing the user to capacitively couple ac signals directly into the ADC without additional active circuitry. For best dynamic performance, the VREF OUT pin should be decoupled to ground with a 0.1  $\mu$ F capacitor (to minimize modulation of the reference voltage) and the bias resistor should be approximately 1 k $\Omega$ . A 1 k $\Omega$  bias resistor (±20%) is included within the AD9057 and may be used to reduce application board size and complexity.

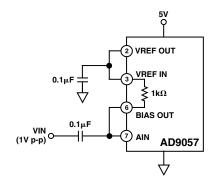


Figure 2. Capacitively Coupled AD9057

Figure 3 shows typical connections for high performance dc biasing using the ADC's internal voltage reference. All components may be powered from a single 5 V supply. In the example, analog input signals are referenced to ground.

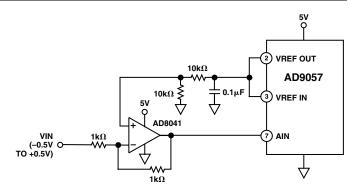


Figure 3. DC-Coupled AD9057 (Inverted VIN)

## Voltage Reference

A stable and accurate 2.5 V voltage reference is built into the AD9057 (VREF OUT). The reference output may be used to set the ADC gain/offset by connecting VREF OUT to VREF IN. The internal reference is capable of providing 300  $\mu$ A of drive current (for dc biasing the analog input or other user circuitry).

Some applications may require greater accuracy, improved temperature performance, or gain adjustments that cannot be obtained using the internal reference. An external voltage may be applied to the VREF IN with VREF OUT disconnected for gain adjustment of up to  $\pm 10\%$  (the VREF IN pin is internally tied directly to the ADC circuitry). ADC gain and offset will vary simultaneously with external reference adjustment with a 1:1 ratio (a 2% or 50 mV adjustment to the 2.5 V reference varies ADC gain by 2% and ADC input range center offset by 50 mV). Theoretical input voltage range versus reference input voltage may be calculated from the following equations:

 $V_{RANGE}$  (p-p) = VREF IN/2.5  $V_{MIDSCALE}$  = VREF IN

 $V_{TOP\text{-}OF\text{-}RANGE} = VREF\ IN + V_{RANGE}/2$  $V_{BOTTOM\text{-}OF\text{-}RANGE} = VREF\ IN - V_{RANGE}/2$ 

## Digital Logic (5 V/3 V Systems)

The digital inputs and outputs of the AD9057 can easily be configured to interface directly with 3 V or 5 V logic systems. The encode and power-down (PWRDN) inputs are CMOS stages with TTL thresholds of 1.5 V, making the inputs compatible with TTL, 5 V CMOS, and 3 V CMOS logic families. As with all high speed data converters, the encode signal should be clean and jitter free to prevent degradation of ADC dynamic performance.

The AD9057's digital outputs will also interface directly with 5 V or 3 V CMOS logic systems. The voltage supply pin  $(V_{\rm DD})$  for these CMOS stages is isolated from the analog  $V_{\rm D}$  voltage supply. By varying the voltage on this supply pin, the digital output high level will change for 5 V or 3 V systems. Optimum SNR is obtained running the outputs at 3 V. Care should be taken to isolate the  $V_{\rm DD}$  supply voltage from the 5 V analog supply to minimize digital noise coupling into the ADC.

REV. D -7-

The AD9057 provides high impedance digital output operation when the ADC is driven into power-down mode (PWRDN, logic high). A 200 ns (minimum) power-down time should be provided before a high impedance characteristic is required at the outputs. A 200 ns power-up period should be provided to ensure accurate ADC output data after reactivation (valid output data is available three clock cycles after the 200 ns delay).

#### **Timing**

The AD9057 is guaranteed to operate with conversion rates from 5 MSPS to 80 MSPS depending on grade. The ADC is designed to operate with an encode duty cycle of 50%, but performance is insensitive to moderate variations. Pulsewidth variations of up to  $\pm 10\%$  (allowing the encode signal to meet the minimum/maximum high/low specifications) will cause no degradation in ADC performance (see Figure 1 timing diagram).

### **Power Dissipation**

The power dissipation of the AD9057 is specified to reflect a typical application setup under the following conditions: analog input is –0.5 dBFS at 10.3 MHz,  $V_D$  is 5 V,  $V_{DD}$  is 3 V, and digital outputs are loaded with 7 pF typical (10 pF maximum). The actual dissipation will vary as these conditions are modified in user applications. TPC 7 shows typical power consumption for the AD9057 versus ADC encode frequency and  $V_{DD}$  supply voltage.

A power-down function allows users to reduce power dissipation when ADC data is not required. A TTL/CMOS high signal (PWRDN) shuts down portions of the ADC and brings total power dissipation to less than 10 mW. The internal band gap voltage reference remains active during power-down mode to minimize ADC reactivation time. If the power-down function is not desired, Pin 1 should be tied to ground.

## APPLICATIONS

The wide analog bandwidth of the AD9057 makes it attractive for a variety of high performance receiver and encoder applications. Figure 4 shows two ADCs in a typical low cost I and Q demodulator implementation for cable, satellite, or wireless LAN modem receivers. The excellent dynamic performance of the ADC at higher analog input frequencies and encode rates empowers users to employ direct IF sampling techniques (refer to TPC 2 spectral plot). IF sampling eliminates or simplifies analog mixer and filter stages to reduce total system cost and power.

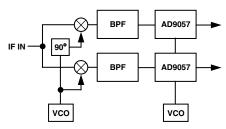


Figure 4. I and Q Digital Receiver

The high sampling rate and analog bandwidth of the AD9057 are ideal for computer RGB video digitizer applications. With a

full-power analog bandwidth of 2× the maximum sampling rate, the ADC provides sufficient pixel-to-pixel transient settling time to ensure accurate 60 MSPS video digitization. Figure 5 shows a typical RGB video digitizer implementation for the AD9057.

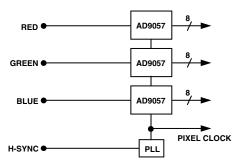


Figure 5. RGB Video Encoder

#### **Evaluation Board**

The AD9057/PCB evaluation board provides an easy-to-use analog/digital interface for the 8-bit, 60 MSPS ADC. The board includes typical hardware configurations for a variety of high speed digitization evaluations. On-board components include the AD9057 (in the 20-lead SSOP package), an optional analog input buffer amplifier, a digital output latch, board timing drivers, an analog reconstruction digital-to-analog converter, and configurable jumpers for ac coupling, dc coupling, and power-down function testing. The board is configured at shipment for dc coupling using the AD9057's internal voltage reference.

For dc-coupled analog input applications, amplifier U2 is configured to operate as a unity gain inverter with adjustable offset for the analog input signal. For full-scale ADC drive, the analog input signal should be 1 V p-p into 50  $\Omega$  (R1) referenced to ground (0 V). The amplifier offsets the analog signal by +VREF (2.5 V typical) to center the voltage for proper ADC input drive. For dc-coupled operation, connect E1 to E2 (analog input to R2) and E11 to E12 (amplifier output to analog input of AD9057) using the board jumper connectors. DC offset of the analog input signal can be modified by adjusting potentiometer R10.

For ac-coupled analog input applications, amplifier U2 is removed from the analog signal path. The analog signal is coupled into the input of the AD9057 through capacitor C2. The ADC pulls analog input bias current from the VREF IN voltage through the 1 k $\Omega$  resistor internal to the AD9057 (BIAS OUT). The analog input signal to the board should be 1 V p-p into 50  $\Omega$  (R1) for full-scale ADC drive. For ac-coupled operation, connect E1 to E3 (analog input A to C2 feedthrough capacitor) and E10 to E12 (C2 to the analog input and internal bias resistor) using the board jumper connectors.

The on-board reference voltage may be used to drive the ADC or an external reference may be applied. To use the internal voltage reference, connect E6 to E5 (VREF OUT to VREF IN). To apply an external voltage reference, connect E4 to E5 (external reference from the REF banana jack to VREF IN). The external voltage reference should be  $2.5 \, \text{V} \pm 10\%$ .

–8– REV. D

The power-down function of the AD9057 can be done through a board jumper connection. Connect E7 to E9 (5 V to PWRDN) for power-down operation. For normal operation, connect E8 to E9 (ground to PWRDN).

The encode signal source should be TTL/CMOS compatible and capable of driving a 50  $\Omega$  termination (R7). The digital outputs of the AD9057 are buffered through latches on the evaluation board (U3) and are available for the user at connector Pins 30 to 37. Latch timing is derived from the ADC encode clock and a digital clocking signal is provided for the board user at connector Pins 2 and 21.

An on-board reconstruction digital-to-analog converter is available for quick evaluations of ADC performance using an oscilloscope or spectrum analyzer. The DAC converts the ADC's digital outputs to an analog signal for examination at the DAC OUT connector. The DAC is clocked at the ADC encode frequency. The AD9760 is a 10-bit/100 MSPS single 5 V supply DAC. The reconstruction signal facilitates quick system trouble-shooting or confirmation of ADC functionality without requiring external digital memory, timing, or display interfaces. The DAC can be used for limited dynamic testing, but customers should note that test results will be based on the combined performance of the ADC and DAC (the best ADC performance will be recognized by evaluating the digital outputs of the ADC directly).

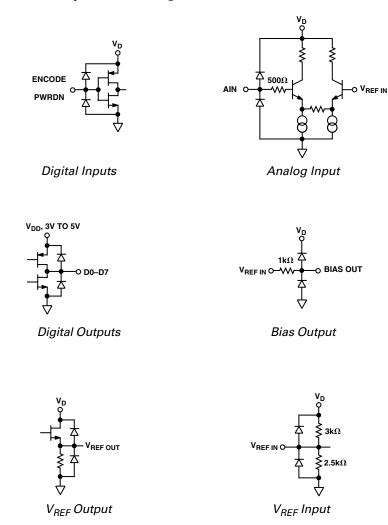


Figure 6. Equivalent Circuits

REV. D -9-

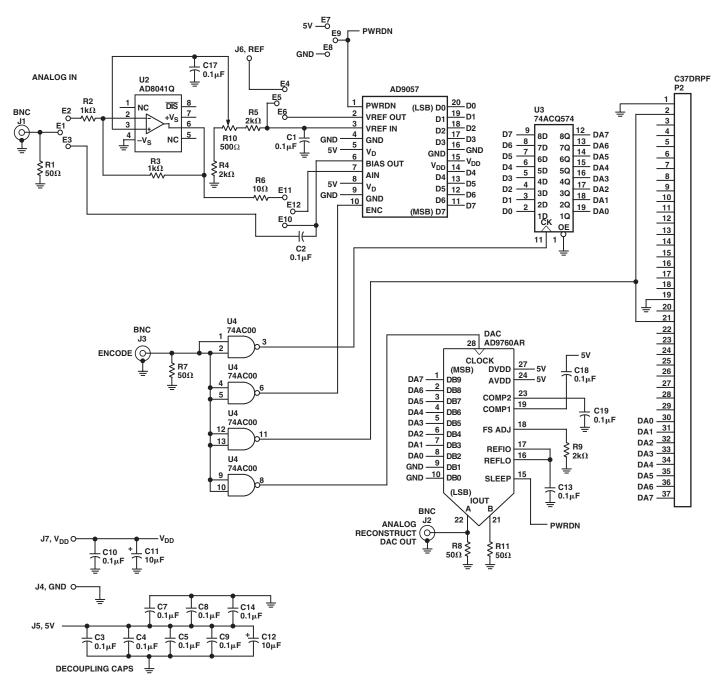
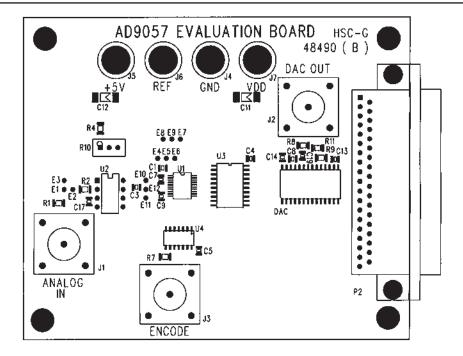


Figure 7. Evaluation Board Schematic



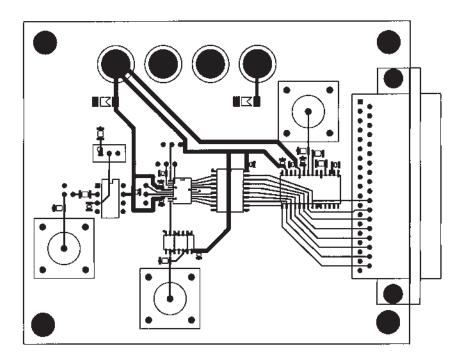


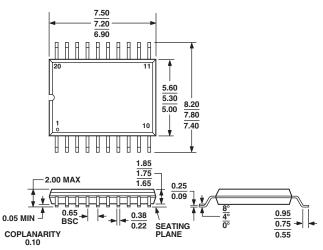
Figure 8. Evaluation Board Layout

REV. D -11-

## **OUTLINE DIMENSIONS**

## 20-Lead Shrink Small Outline Package [SSOP] (RS-20)

Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-150AE

## **Revision History**

Location	Page
5/03—Data Sheet changed from REV. C to REV. D.	
Change to SPECIFICATIONS	
Updated OUTLINE DIMENSIONS	
9/01—Data Sheet changed from REV. B to REV. C.	
Edit to ABSOLUTE MAXIMUM RATINGS	

-12- REV. D